

# BFG325W/XR

# NPN 14 GHz wideband transistor Rev. 01 — 2 February 2005

**Product data sheet** 

### **Product profile**

### 1.1 General description

NPN silicon planar epitaxial transistor in a 4-pin dual-emitter SOT343R plastic package.

### 1.2 Features

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability

### 1.3 Applications

- Intended for Radio Frequency (RF) front end applications in the GHz range, such as:
  - analog and digital cellular telephones
  - ◆ cordless telephones (Cordless Telephone (CT), Personal Communication Network (PCN), Digital Enhanced Cordless Telecommunications (DECT), etc.)
  - radar detectors
  - pagers
  - ◆ Satellite Antenna TeleVision (SATV) tuners

#### 1.4 Quick reference data

Table 1: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-	15	V
$V_{CEO}$	collector-emitter voltage	open base	-	-	6	V
I <sub>C</sub>	collector current (DC)		-	-	35	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> ≤ 90 °C	<u>[1]</u> _	-	210	mW
h <sub>FE</sub>	DC current gain	$I_C = 15 \text{ mA}; V_{CE} = 3 \text{ V};$ $T_j = 25 ^{\circ}\text{C}$	60	100	200	
C <sub>CBS</sub>	collector-base capacitance	$V_{CB} = 5 \text{ V}; f = 1 \text{ MHz};$ emitter grounded	-	0.27	0.4	pF
f <sub>T</sub>	transition frequency	$I_C$ = 15 mA; $V_{CE}$ = 3 V; f = 1 GHz; $T_{amb}$ = 25 °C	-	14	-	GHz
G <sub>max</sub>	maximum power gain [2]	$I_C = 15 \text{ mA}; V_{CE} = 3 \text{ V};$ $f = 1.8 \text{ GHz}; T_{amb} = 25 ^{\circ}\text{C}$	-	18.3	-	dB



Table 1: Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
S <sub>21</sub>   <sup>2</sup>	insertion power gain	$I_C$ = 15 mA; $V_{CE}$ = 3 V; f = 1.8 GHz; $T_{amb}$ = 25 °C; $Z_S$ = $Z_L$ = 50 $\Omega$	-	14	-	dB
NF	noise figure	$\Gamma_{\text{S}} = \Gamma_{\text{opt}}$ ; $I_{\text{C}} = 3 \text{ mA}$ ; $V_{\text{CE}} = 3 \text{ V}$ ; $f = 2 \text{ GHz}$	-	1.1	-	dB

- [1]  $T_{sp}$  is the temperature at the soldering point of the collector pin.
- [2]  $G_{max}$  is the maximum power gain, if K > 1. If K < 1 then  $G_{max}$  = MSG, see Figure 4.

## 2. Pinning information

Table 2: Pinning

Pin	Description	Simplified outline	Symbol
1	collector		
2	emitter	3 4	1
3	base		3 —
4	emitter		2, 4
		2 1	sym086

## 3. Ordering information

**Table 3: Ordering information** 

Type number	Package					
	Name	Description	Version			
BFG325W/XR	-	plastic surface mounted package; reverse pinning; 4 leads	SOT343R			

### 4. Marking

Table 4: Marking codes

Type number	Marking code [1]
BFG325W/XR	A8*

[1] \* = p: made in Hong Kong.

# 5. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	15	V
$V_{CEO}$	collector-emitter voltage	open base	-	6	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	2	V

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 Table 5:
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
I <sub>C</sub>	collector current (DC)		-	35	mΑ
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> ≤ 90 °C	<u>[1]</u> _	210	mW
T <sub>stg</sub>	storage temperature		-65	+175	°C
Tj	junction temperature		-	175	°C

<sup>[1]</sup>  $T_{sp}$  is the temperature at the soldering point of the collector pin.

### 6. Thermal characteristics

Table 6: Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	$T_{sp} \le 90  ^{\circ}C$	<u>[1]</u> 403	K/W

<sup>[1]</sup>  $T_{sp}$  is the temperature at the soldering point of the collector pin.

### 7. Characteristics

**Table 7: Characteristics** 

 $T_i = 25 \,^{\circ}C$ ; unless otherwise specified.

,	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	I <sub>E</sub> = 0 A; V <sub>CB</sub> = 5 V	-	-	15	nA
h <sub>FE</sub>	DC current gain	$I_C = 15 \text{ mA}; V_{CE} = 3 \text{ V}$	60	100	200	
C <sub>CBS</sub>	collector-base capacitance	$V_{CB} = 5 \text{ V}$ ; f = 1 MHz; emitter grounded	-	0.27	0.4	pF
C <sub>CES</sub>	collector-emitter capacitance	V <sub>CE</sub> = 5 V; f = 1 MHz; base grounded	-	0.22	-	pF
C <sub>EBS</sub>	emitter-base capacitance	V <sub>EB</sub> = 0.5 V; f = 1 MHz; collector grounded	-	0.49	-	pF
f <sub>T</sub>	transition frequency	$I_C$ = 15 mA; $V_{CE}$ = 3 V; f = 1 GHz; $T_{amb}$ = 25 °C	-	14	-	GHz
G <sub>max</sub>	maximum power gain [1]	$I_C$ = 15 mA; $V_{CE}$ = 3 V; f = 1.8 GHz; $T_{amb}$ = 25 °C	-	18.3	-	dB
s <sub>21</sub>   <sup>2</sup>	insertion power gain	$I_C$ = 15 mA; $V_{CE}$ = 3 V; $T_{amb}$ = 25 °C; $Z_S$ = $Z_L$ = 50 $\Omega$				
		f = 1.8 GHz	-	14	-	dB
		f = 3 GHz	-	10	-	dB
NF	noise figure	$\Gamma_{\text{S}}$ = $\Gamma_{\text{opt}}$ ; $I_{\text{C}}$ = 3 mA; $V_{\text{CE}}$ = 3 V; f = 2 GHz	-	1.1	-	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	$I_C$ = 15 mA; $V_{CE}$ = 3 V; f = 1.8 GHz; $T_{amb}$ = 25 °C; $Z_S$ = $Z_L$ = 50 $\Omega$	-	8.7	-	dBm
IP3	third order intercept point	$I_C$ = 15 mA; $V_{CE}$ = 3 V; f = 1.8 GHz; $T_{amb}$ = 25 °C; $Z_S$ = $Z_L$ = 50 $\Omega$	-	19.4	-	dBm

[1]  $G_{max}$  is the maximum power gain, if K > 1. If K < 1 then  $G_{max} = MSG$ , see Figure 4.

K is the Rollet stability factor: 
$$K = \frac{I + \left| Ds \right|^2 - \left| s_{1I} \right|^2 - \left| s_{22} \right|^2}{2 \times \left| s_{2I} \right| \times \left| s_{12} \right|} \text{ where } Ds = s_{II} \times s_{22} - s_{I2} \times s_{2I} \,.$$

MSG = maximum stable gain.

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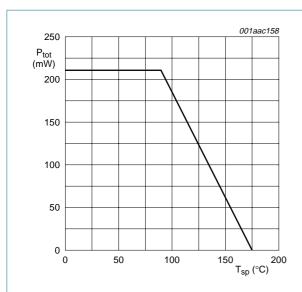


Fig 1. Power derating curve

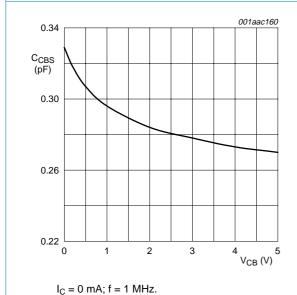


Fig 3. Collector-base capacitance as a function of collector-base voltage; typical values

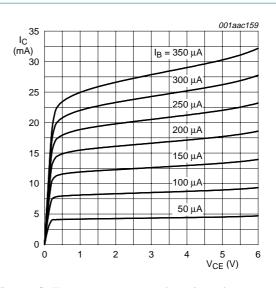


Fig 2. Collector current as a function of collector-emitter voltage; typical values

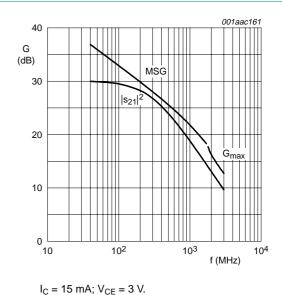
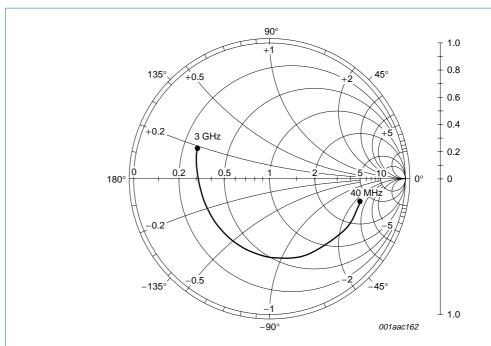
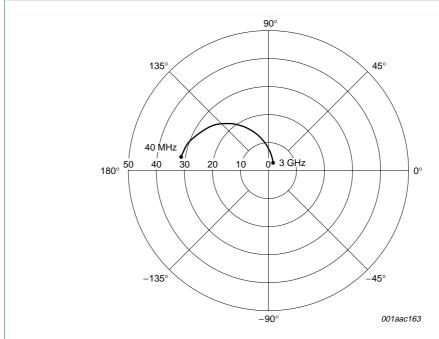


Fig 4. Gain as a function of frequency; typical values



 $V_{CE}$  = 3 V;  $I_{C}$  = 15 mA;  $Z_{o}$  = 50  $\Omega.$ 

Fig 5. Common emitter input reflection coefficient (s<sub>11</sub>); typical values



 $V_{CE} = 3 \text{ V}$ ;  $I_{C} = 15 \text{ mA}$ .

Fig 6. Common emitter forward transmission coefficient ( $s_{21}$ ); typical values

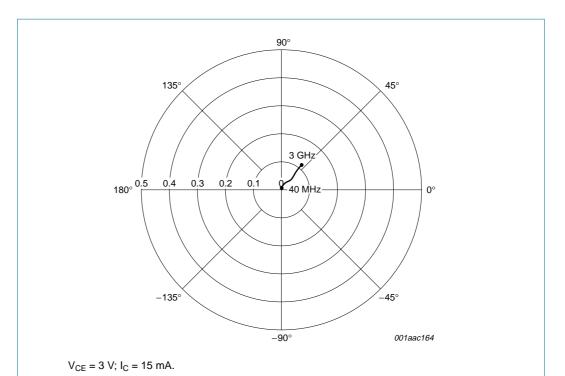
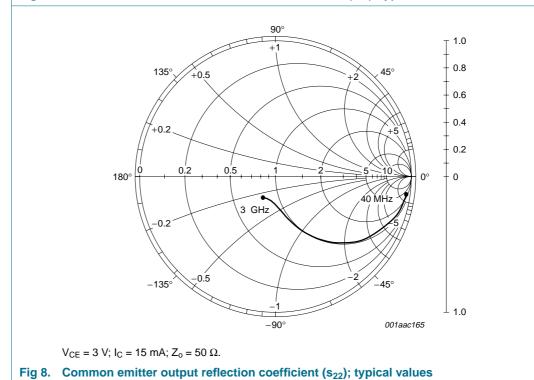


Fig 7. Common emitter reverse transmission coefficient  $(s_{12})$ ; typical values



# 8. Application information

Table 8: SPICE parameters of the BFG325 DIE

1       IS       26.6       aA         2       BF       200       -         3       NF       1       -         4       VAF       40       V         5       IKF       105       mA         6       ISE       2.3       fA         7       NE       2.114       -         8       BR       10       -         9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       - <td< th=""><th>Sequence</th><th>Parameter</th><th>Value</th><th>Unit</th></td<>	Sequence	Parameter	Value	Unit
3       NF       1       -         4       VAF       40       V         5       IKF       105       mA         6       ISE       2.3       fA         7       NE       2.114       -         8       BR       10       -         9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       IF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       IF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       - <td< td=""><td>1</td><td>IS</td><td>26.6</td><td>аА</td></td<>	1	IS	26.6	аА
4       VAF       40       V         5       IKF       105       mA         6       ISE       2.3       fA         7       NE       2.114       -         8       BR       10       -         9       NR       1       -         10       VAR       1       -         10       VAR       1.5       -         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         <	2	BF	200	-
5       IKF       105       mA         6       ISE       2.3       fA         7       NE       2.114       -         8       BR       10       -         9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       100       -	3	NF	1	-
6       ISE       2.3       fA         7       NE       2.114       -         8       BR       10       -         9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V	4	VAF	40	V
7       NE       2.114       -         8       BR       10       -         9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA	5	IKF	105	mA
8       BR       10       -         9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       0       deg         30       TR       0       ns	6	ISE	2.3	fA
9       NR       1       -         10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       n	7	NE	2.114	-
10       VAR       2.5       V         11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       -         32       AF       1       -	8	BR	10	-
11       IKR       10       A         12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -	9	NR	1	-
12       ISC       0       aA         13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       -         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C	10	VAR	2.5	V
13       NC       1.5       -         14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV <tr< td=""><td>11</td><td>IKR</td><td>10</td><td>A</td></tr<>	11	IKR	10	A
14       RB       3.6       Ω         15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -	12	ISC	0	aA
15       RE       1.5       Ω         16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       - <td>13</td> <td>NC</td> <td>1.5</td> <td>-</td>	13	NC	1.5	-
16       RC       2.6       Ω         17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	14	RB	3.6	Ω
17       CJE       185.6       fF         18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	15	RE	1.5	Ω
18       VJE       890       mV         19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	16	RC	2.6	Ω
19       MJE       0.294       -         20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	17	CJE	185.6	fF
20       CJC       77.06       fF         21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	18	VJE	890	mV
21       VJC       601       mV         22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	19	MJE	0.294	-
22       MJC       0.159       -         23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	20	CJC	77.06	fF
23       XCJC       1       -         24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	21	VJC	601	mV
24       FC       0.7       -         25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	22	MJC	0.159	-
25       TF       8.1       ps         26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	23	XCJC	1	-
26       XTF       10       -         27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	24	FC	0.7	-
27       VTF       1000       V         28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	25	TF	8.1	ps
28       ITF       150       mA         29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	26	XTF	10	-
29       PTF       0       deg         30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	27	VTF	1000	V
30       TR       0       ns         31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	28	ITF	150	mA
31       KF       0       -         32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	29	PTF	0	deg
32       AF       1       -         33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	30	TR	0	ns
33       TNOM       25       °C         34       EG       1.014       eV         35       XTB       0       -         36       XTI       8       -	31	KF	0	-
34     EG     1.014     eV       35     XTB     0     -       36     XTI     8     -	32	AF	1	-
35 XTB 0 - 36 XTI 8 -	33	TNOM	25	°C
36 XTI 8 -	34	EG	1.014	eV
	35	XTB	0	-
37 Q1.AREA 2.5 -	36	XTI	8	-
	37	Q1.AREA	2.5	-

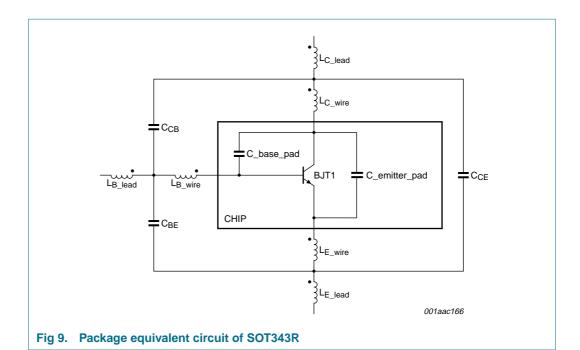


Table 9: List of components; see Figure 9

Designation	Value	Unit
C <sub>CB</sub>	2	fF
C <sub>BE</sub>	80	fF
C <sub>CE</sub>	80	fF
C_base_pad	67	fF
C_emitter_pad	142	fF
L <sub>C_wire</sub>	0.767	nH
L <sub>B_wire</sub>	0.842	nH
L <sub>E_wire</sub>	0.212	nH
L <sub>C_lead</sub>	0.28	nH
L <sub>B_lead</sub>	0.281	nH
L <sub>E_lead</sub>	0.1	nH



### 9. Package outline

### Plastic surface mounted package; reverse pinning; 4 leads

SOT343R

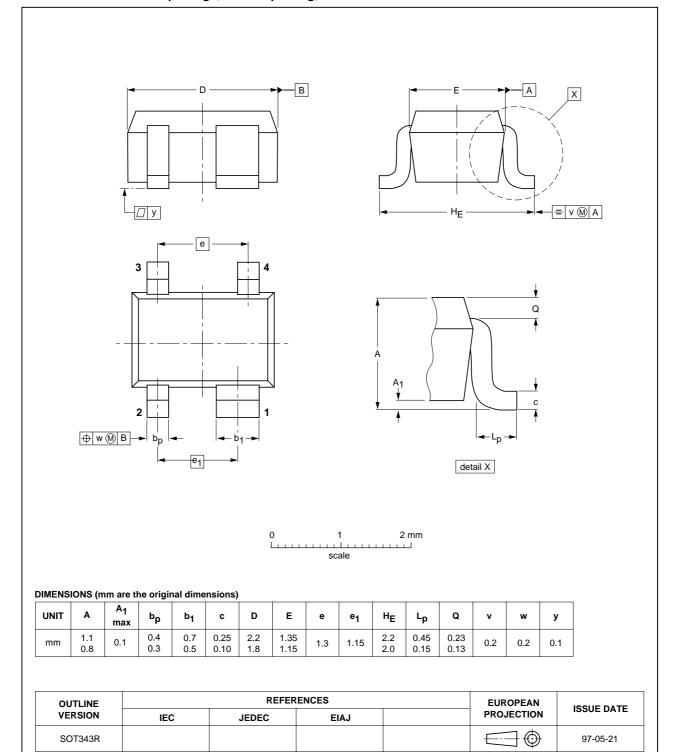


Fig 10. Package outline SOT343R



**NPN 14 GHz wideband transistor** 

# 10. Revision history

### Table 10: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BFG325W_XR_1	20050202	Product data sheet	-	9397 750 14246	-

NPN 14 GHz wideband transistor



Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- [2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- [3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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### **Philips Semiconductors**

# BFG325W/XR

**NPN 14 GHz wideband transistor** 

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